

SAMTM Data Sheet SAM-1064-9-47ps-x, λ = 1064 nm

Laser wavelength $\lambda = 1064 \text{ nm}$

High reflection band $\lambda = 1010 ... 1110 \text{ nm}$

Reflectance at 808 nm R_{808} = 67 % Absorbance A_0 = 9 % Modulation depth ΔR = 5.7 % Non-saturable loss A_{ns} = 3.3 % Saturation fluence Φ_{sat} = 49 μ J/cm²

Relaxation time constant $\tau \sim 47 \text{ ps}$

Damage threshold $\Phi = 2.5 \text{ mJ/cm}^2$

Chip area 4.0 mm x 4.0 mm; other dimensions on request

Chip thickness 450 µm

Dielectric coating HR @ 808 nm and AR @ 1064 nm

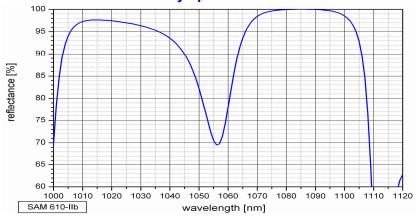
Mounting option **x** denotes the type of mounting as follows:

 $\mathbf{x} = 0$ unmounted $\mathbf{x} = 12.7 \, \mathrm{g}$ glued on a copper heat sink with 12.7 mm \varnothing

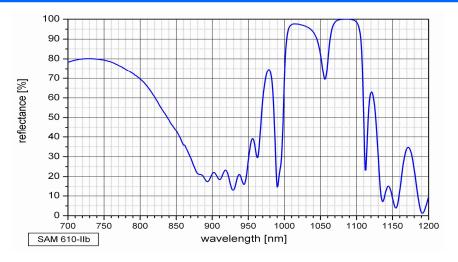
 $x = 25.4 \, \mathrm{g}$ glued on a copper heat sink with 25.4 mm \varnothing $x = 12.7 \, \mathrm{s}$ soldered on a copper heat sink with 12.7 mm \varnothing $x = 25.4 \, \mathrm{s}$ soldered on a copper heat sink with 25.4 mm \varnothing

x = 25.4 w soldered on a water cooled copper heat sink with 25.4 mm ∅ x = FC mounted on a 1 m monomode fiber cable with FC connector

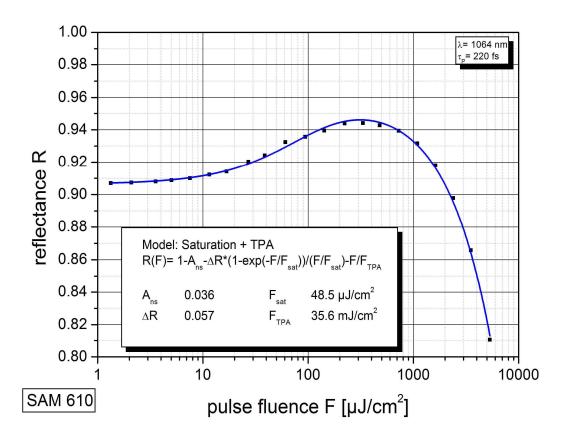
Low intensity spectral reflectance







Saturation measurement





Pump-probe measurement

